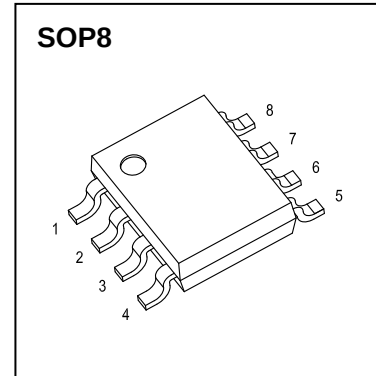


**SOP8 Plastic-Encapsulate MOSFETS****CJQ12SN06 N-Channel Power MOSFET**

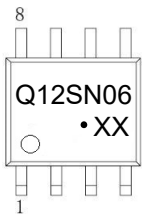
$V_{(BR)DSS}$	$R_{DS(on)}$ TYP	I_D
60	11mΩ@10V	12A
	14mΩ@4.5V	

**DESCRIPTION**

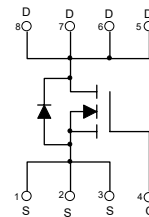
The CJQ12SN06 uses shielded gate trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications

APPLICATIONS

- High side switch in SMPS
- Load Switch

MARKING

Q12SN06= Device code
Solid dot=Pin1 indicator
Solid dot = Green molding compound device,
if none, the normal device
XX=Date Code

Equivalent Circuit**MAXIMUM RATINGS ($T_a=25^{\circ}\text{C}$ unless otherwise noted)**

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V_{DS}	60	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current	I_D	12	A
Pulsed Drain Current	I_{DM}	40	A
Single Pulsed Avalanche Energy	$E_{AS}^{(1)}$	22	mJ
Power Dissipation	P_D	1.4	W
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	89	$^{\circ}\text{C/W}$
Junction Temperature	T_J	150	$^{\circ}\text{C}$
Storage Temperature Range	T_{stg}	-55 ~ +150	$^{\circ}\text{C}$
Lead Temperature for Soldering Purposes(1/8" from case for 10s)	T_L	260	$^{\circ}\text{C}$

(1). E_{AS} condition: $V_{DD}=20\text{V}$, $L=0.4\text{mH}$, $R_G=25\Omega$, Starting $T_J = 25^{\circ}\text{C}$

MOSFET ELECTRICAL CHARACTERISTICS

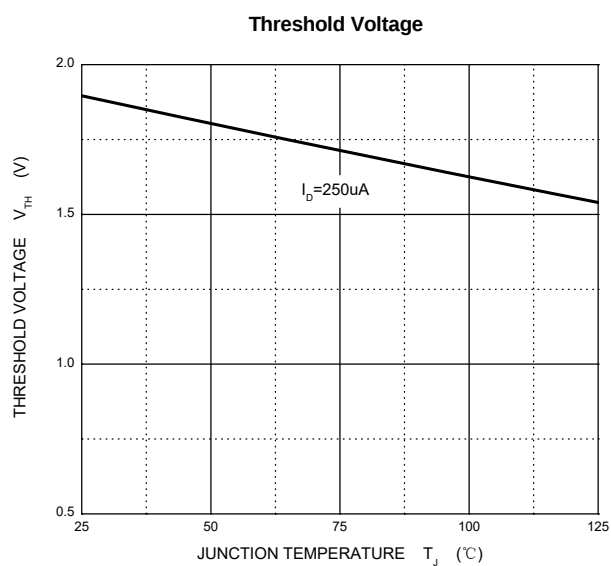
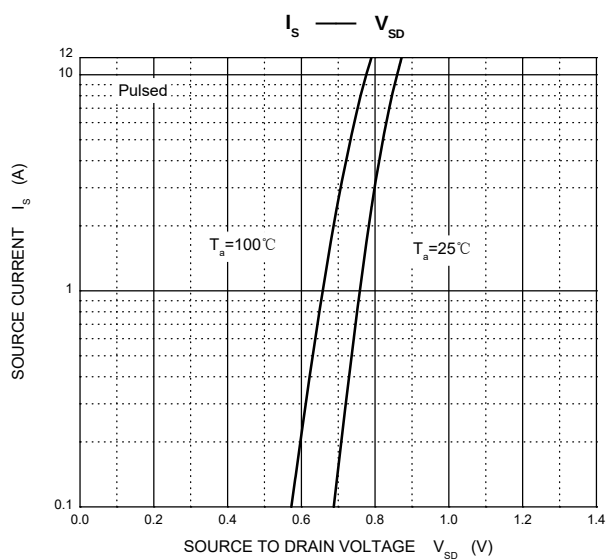
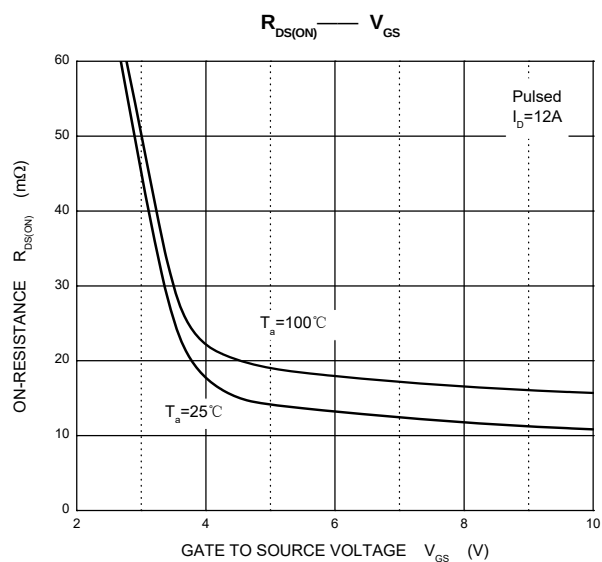
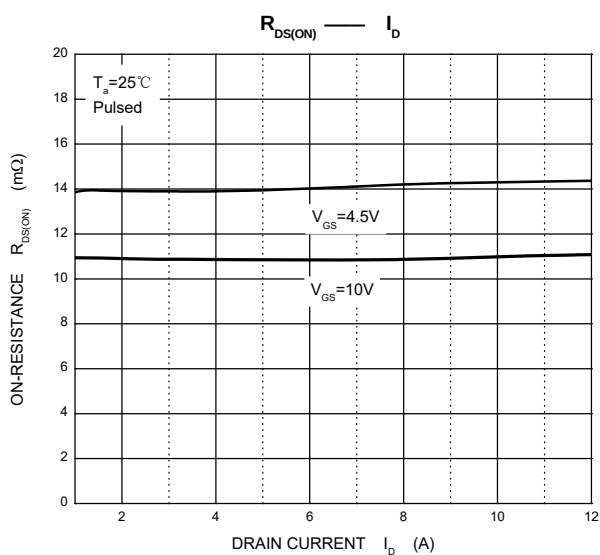
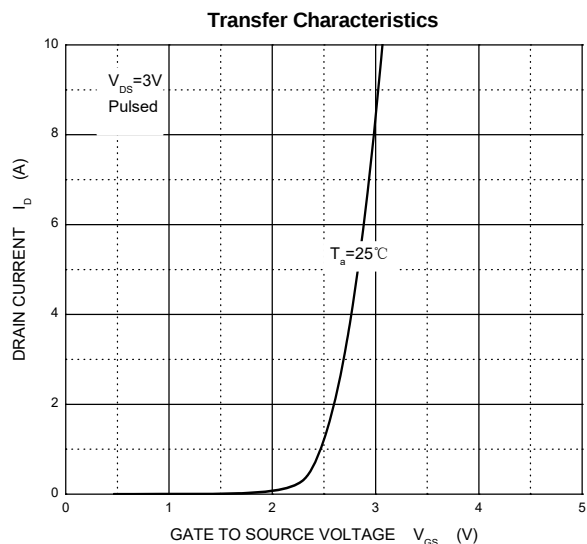
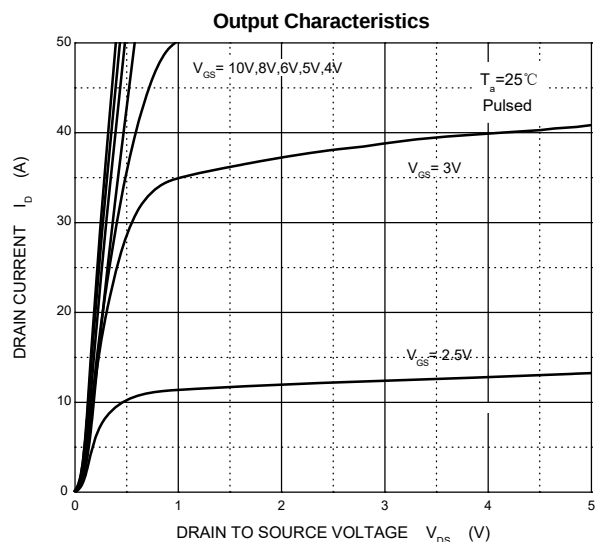
$T_a = 25^\circ\text{C}$ unless otherwise specified

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Off characteristics						
Drain-source breakdown voltage	V _{(BR) DSS}	V _{GS} = 0V, I _D =250μA	60			V
Zero gate voltage drain current	I _{DSS}	V _{DS} =45V, V _{GS} =0V			1	μA
Gate-body leakage current	I _{GSS}	V _{DS} =0V, V _{GS} =±20V			±100	nA
On characteristics (note1)						
Gate-threshold voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250μA	1.4	1.9	2.4	V
Static drain-source on-sate resistance	R _{DS(on)}	V _{GS} =10V, I _D =12A		11	14	mΩ
		V _{GS} =4.5V, I _D =10A		14	21	mΩ
Forward transconductance	g _{FS}	V _{DS} =5V, I _D =10A		63		S
Dynamic characteristics (note 2)						
Input capacitance	C _{iss}	V _{DS} =30V,V _{GS} =0V, f =1MHz		1000	2000	pF
Output capacitance	C _{oss}			265	530	
Reverse transfer capacitance	C _{rss}			11	22	
Switching characteristics (note 2)						
Total gate charge	Q _g	V _{DS} =30V, V _{GS} =10V, I _D =10A		38	76	nC
Gate-source charge	Q _{gs}			15	30	
Gate-drain charge	Q _{gd}			6	12	
Turn-on delay time	t _{d(on)}	V _{DD} =30V,I _D =10A, V _{GS} =10V,R _G =10Ω		9	18	ns
Turn-on rise time	t _r			5	10	
Turn-off delay time	t _{d(off)}			27	54	
Turn-off fall time	t _f			5	10	
Gate Resistance	R _g	f =1MHz, V _{DS} =0V, V _{GS} =0V,		2.5		Ω
Drain-Source Diode Characteristics						
Drain-source diode forward voltage(note1)	V _{SD}	V _{GS} =0V, I _S =10A			1.2	V
Continuous drain-source diode forward current	I _S				10	A
Pulsed drain-source diode forward current	I _{SM}				35	A

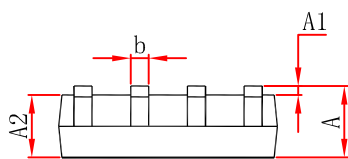
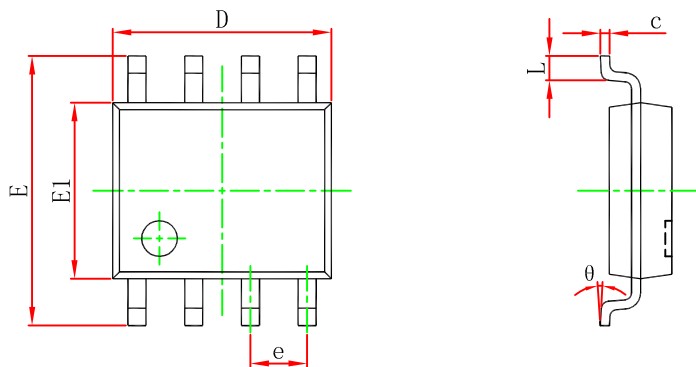
Notes:

1. Pulse Test : Pulse Width $\leq 300\mu s$, duty cycle $\leq 2\%$.
2. Guaranteed by design, not subject to production testing.

Typical Characteristics

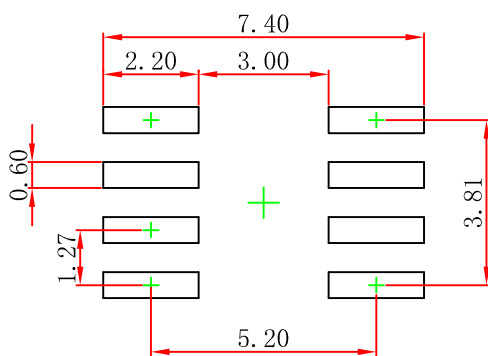


SOP8 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.450	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.007	0.010
D	4.700	5.100	0.185	0.201
e	1.270 (BSC)		0.050 (BSC)	
E	5.800	6.200	0.228	0.244
E1	3.800	4.000	0.150	0.157
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

SOP8 Suggested Pad Layout



Note:

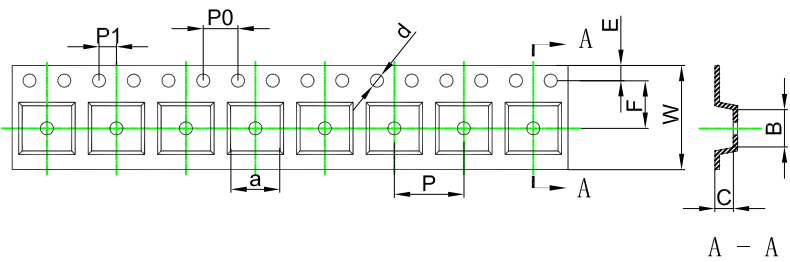
1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$.
3. The pad layout is for reference purposes only.

NOTICE

JSCJ reserves the right to make modifications, enhancements, improvements, corrections or other changes without further notice to any product herein. JSCJ does not assume any liability arising out of the application or use of any product described herein.

SOP8 Tape and Reel

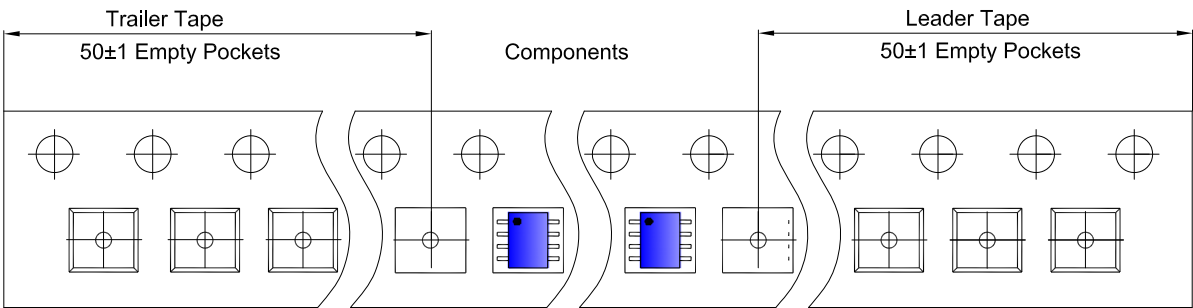
SOP8 Embossed Carrier Tape



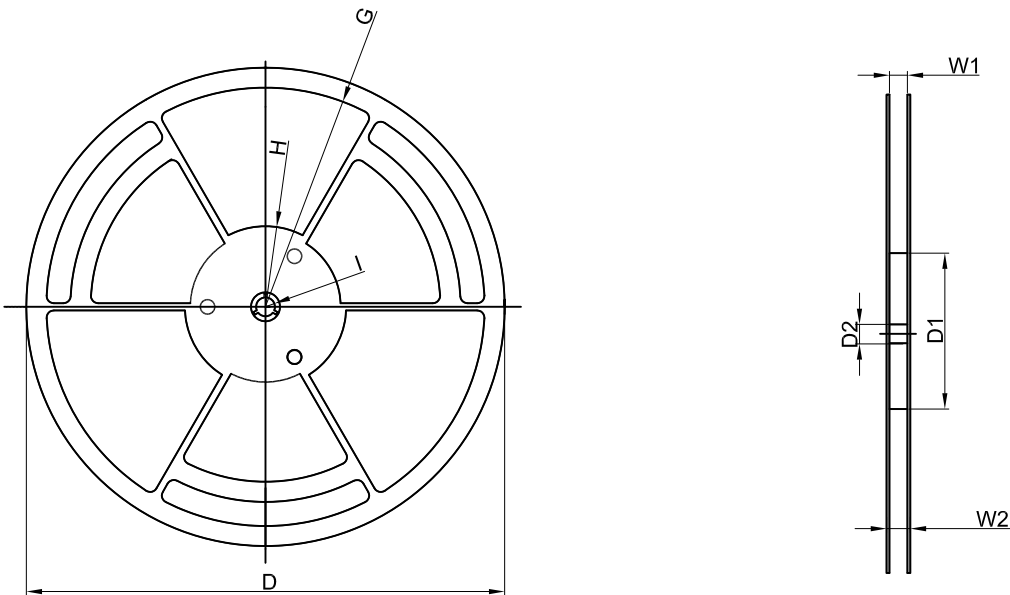
Packaging Description:
SOP8 parts are shipped in tape. The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Heat Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 2,500 units per 13" or 33cm diameter reel. The reels are clear in color and is made of polystyrene plastic (anti-static coated).
ALL DIM IN mm

Dimensions are in millimeter										
Pkg type	a	B	C	d	E	F	P0	P	P1	W
SOP8	6.40	5.40	2.10	Ø1.50	1.75	5.50	4.00	8.00	2.00	12.00

SOP8 Tape Leader and Trailer



SOP8 Reel



Dimensions are in millimeter								
Reel Option	D	D1	D2	G	H	I	W1	W2
13"Dia	Ø330.00	100.00	13.00	R151.00	R56.00	R6.50	12.40	17.60

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)	G.W.(kg)
4,000 pcs	13 inch	8,000 pcs	360×360×65	64,000 pcs	565×380×390	